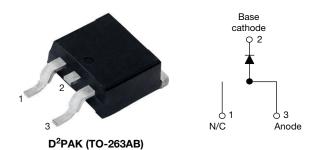
VS-18TQ035S-M3, VS-18TQ040S-M3, VS-18TQ045S-M3

Vishay Semiconductors

RoHS

COMPLIANT

High Performance Schottky Rectifier, 18 A



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SHA

PRIMARY CHARACTERISTICS				
I _{F(AV)}	18 A			
V _R	35 V, 40 V, 45 V			
V _F at I _F	0.53 V			
I _{RM}	25 mA at 125 °C			
T _J max.	175 °C			
E _{AS}	24 mJ			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Single			

FEATURES

- 175 °C T_J operation
- Low forward voltage drop



- HALOGEN • High purity, high temperature epoxy FREE encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-18TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	18	А			
V _{RRM}	Range	35 to 45	V			
I _{FSM}	t _p = 5 μs sine	1800	A			
V _F	18 A _{pk} , T _J = 125 °C	0.53	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-18TQ035S-M3	VS-18TQ040S-M3	VS-18TQ045S-M3	UNITS	
Maximum DC reverse voltage	V _R	35	40	45	V	
Maximum working peak reverse voltage	V _{RWM}		40	4	v	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 149 °C	18	А			
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	1800			
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	390	A		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	А		

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VS-18TQ035S-M3, VS-18TQ040S-M3, VS-18TQ045S-M3

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		18 A	T.I = 25 °C	0.60			
Maximum forward voltage drop See fig. 1	V _{EM} ⁽¹⁾	36 A	1j=25 C	0.72	v		
	V FM (")	18 A	T.I = 125 °C	0.53			
		36 A	1j = 125 C	0.67			
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2.5	mA		
See fig. 2	IRM ()	T _J = 125 °C	V _R = naleu V _R	25	IIIA		
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal ran	1400	pF			
Typical series inductance	LS	Measured lead to lead 5 r	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/					

Note

ISHAY

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum junction and storage temperature rang	e	T _J , T _{Stg}		-55 to 175	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	°C/W		
Approvimete weight				2	g		
Approximate weight				0.07	oz.		
Manuatina tanana	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf ∙ in)		
Marking device				18TQ035S			
			Case style D ² PAK (TO-263AB)	18TQ	040S		
				18TQ	045S		

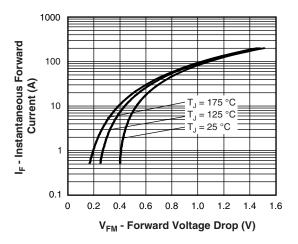


Fig. 1 - Maximum Forward Voltage Drop Characteristics

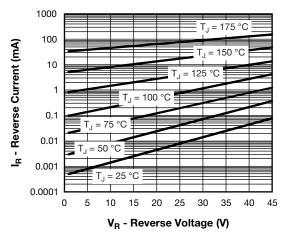


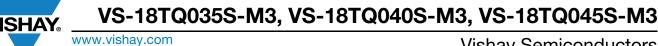
Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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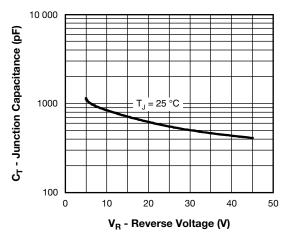
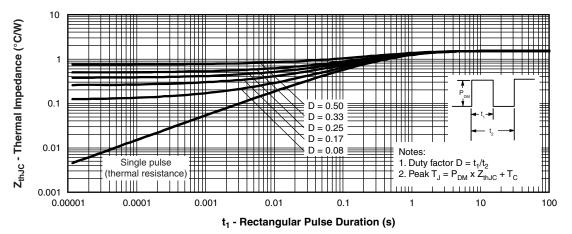
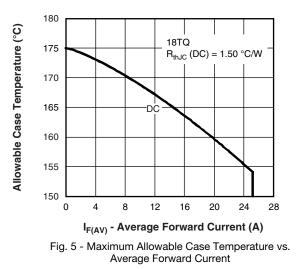
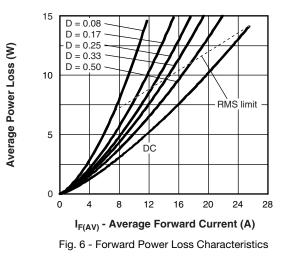


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage







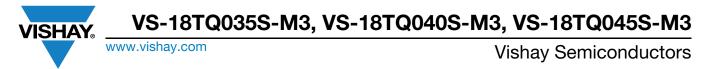


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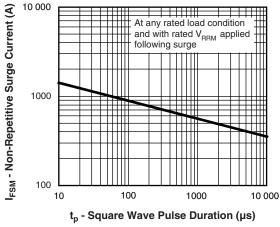
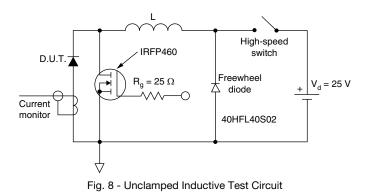
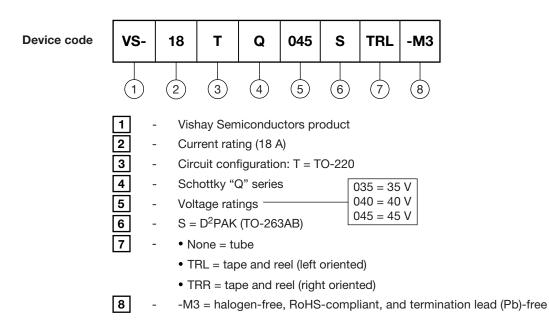


Fig. 7 - Maximum Non-Repetitive Surge Current



ORDERING INFORMATION TABLE



VS-18TQ035S-M3, VS-18TQ040S-M3, VS-18TQ045S-M3

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ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-18TQ035S-M3	50	1000	Antistatic plastic tubes				
VS-18TQ035STRR-M3	800	800	13" diameter reel				
VS-18TQ035STRL-M3	800	800	13" diameter reel				
VS-18TQ040S-M3	50	1000	Antistatic plastic tubes				
VS-18TQ040STRR-M3	800	800	13" diameter reel				
VS-18TQ040STRL-M3	800	800	13" diameter reel				
VS-18TQ045S-M3	50	1000	Antistatic plastic tubes				
VS-18TQ045STRR-M3	800	800	13" diameter reel				
VS-18TQ045STRL-M3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			
SPICE model	www.vishay.com/doc?96209			

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		ETERS INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

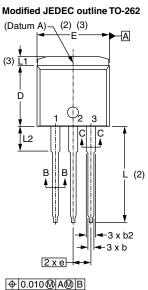


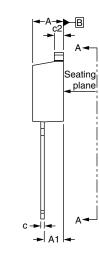
Outline Dimensions

Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches

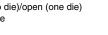


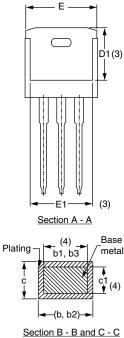


Lead assignments



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

SYMPOL		ETERS	INC	CHES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

Revision: 04-Oct-10

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

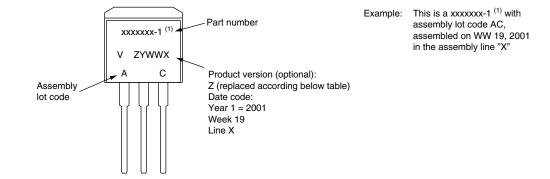
⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

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TO-262



Note

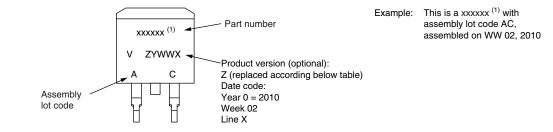
⁽¹⁾ If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z) PRODUCT DEFINITION			
A Termination lead (Pb)-free			
В	Totally lead (Pb)-free		
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free		
Ν	Halogen-free, RoHS-compliant and totally lead (Pb)-free		
G	Green		



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D²PAK



Note

⁽¹⁾ If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
A	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free
G	Green



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